NSN 5962-01-201-6198

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
High impedance and w/active pull-up and w/enable and programmable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Input Circuit Pattern:
17 input
Current Rating Per Characteristic:
180.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, high to low level output and 80.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
A458a0